

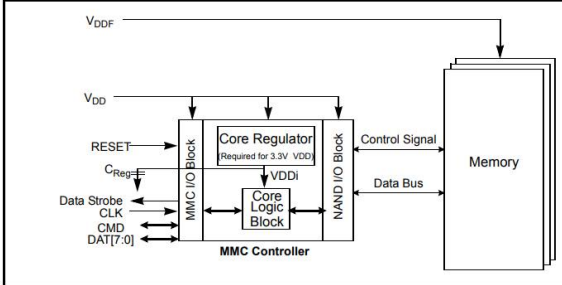
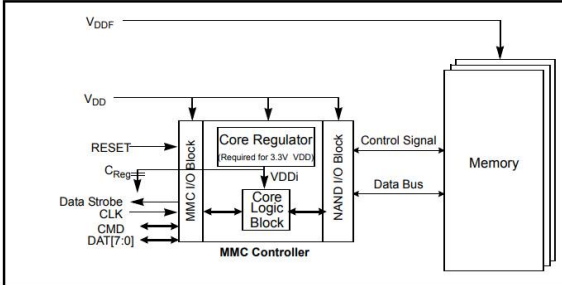
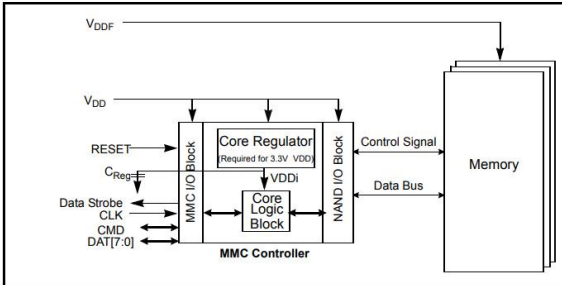
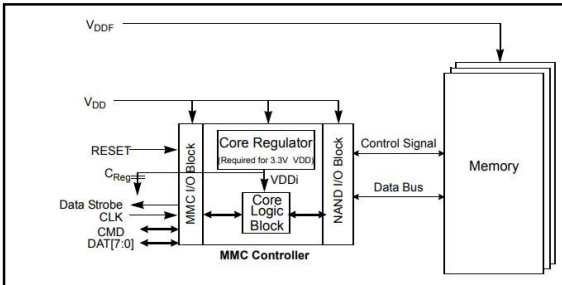
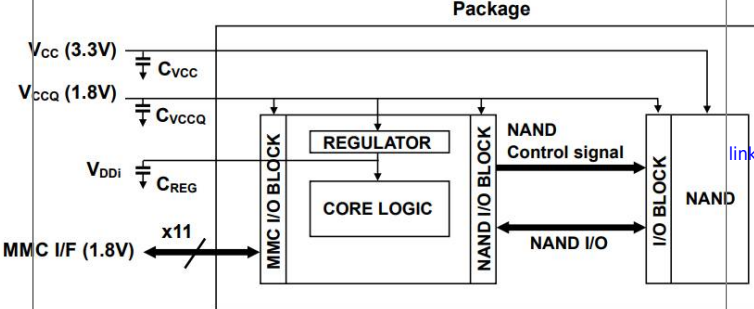
## Содержание

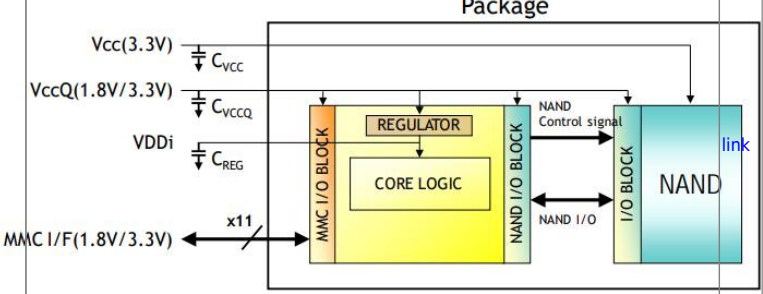
<b>eMMC</b> .....	3
Manufacturers .....	3



# eMMC

## Manufacturers

P\N	MFG	Dens	CASE	Interface	Memory Struct	Link
KLM8G1GETF-B041	SAMSUNG	8GB	153FBGA	VDD (1.70V ~ 1.95V or 2.7V ~ 3.6V)	- eMMC consists of NAND Flash and Controller. V <sub>DD</sub> (V <sub>CCQ</sub> ) is for Controller power and V <sub>DDF</sub> (V <sub>CC</sub> ) is for flash power  	<a href="#">link</a>
KLMAG1JETD-B041	SAMSUNG	16GB	153FBGA	VDD (1.70V ~ 1.95V or 2.7V ~ 3.6V)	- eMMC consists of NAND Flash and Controller. V <sub>DD</sub> (V <sub>CCQ</sub> ) is for Controller power and V <sub>DDF</sub> (V <sub>CC</sub> ) is for flash power  	<a href="#">link</a>
KLMBG2JETD-B041	SAMSUNG	32GB	153FBGA	VDD (1.70V ~ 1.95V or 2.7V ~ 3.6V)	- eMMC consists of NAND Flash and Controller. V <sub>DD</sub> (V <sub>CCQ</sub> ) is for Controller power and V <sub>DDF</sub> (V <sub>CC</sub> ) is for flash power  	<a href="#">link</a>
KLMSG4JETD-B041	SAMSUNG	64GB	153FBGA	VDD (1.70V ~ 1.95V or 2.7V ~ 3.6V)	- eMMC consists of NAND Flash and Controller. V <sub>DD</sub> (V <sub>CCQ</sub> ) is for Controller power and V <sub>DDF</sub> (V <sub>CC</sub> ) is for flash power  	<a href="#">link</a>
THGAMRG7T13BAIL	KIOXIA	16GB	153FBGA	VCCQ = 1.7V to 1.95V VCC 2.7V ~ 3.6V	- eMMC consists of NAND Flash and Controller. V <sub>DD</sub> (V <sub>CCQ</sub> ) is for Controller power and V <sub>DDF</sub> (V <sub>CC</sub> ) is for flash power  	<a href="#">link</a>

P\N	MFG	Dens	CASE	Interface	Memory	Struct	Link
THGBMNG5D1LBAIL	KIOXIA	4GB	153FBGA	VCCQ = 1.7V to 1.95V / 2.7V to 3.6V	VCC 2.7V / 3.6V		link